## N-Channel 40-V (D-S) MOSFET

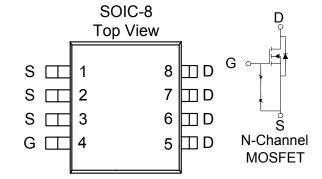
These miniature surface mount MOSFETs utilize a high cell density trench process to provide low  $r_{DS(on)}$  and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

•	Low r <sub>DS(on)</sub> provides higher efficiency and
	extends battery life

- Low thermal impedance copper leadframe SOIC-8 saves board space
- Fast switching speed
- High performance trench technology



PRODUCT SUMMARY				
$V_{DS}(V)$	$r_{DS(on)} m(\Omega)$	$I_D(A)$		
40	$32@V_{CS} = 10V$	8.1		
40	$44@V_{CS}=4.5V$	6.9		



ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25 °C UNLESS OTHERWSE NOTED)					
Parameter		Symbol	Limit	Units	
Drain-Source Voltage			40	V	
Cate-Source Voltage			±20	v	
Continue a Dunius Commund <sup>a</sup>	T <sub>A</sub> =25°C	T_	±8.1		
Continuous Drain Current <sup>a</sup>	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	1D	±6.6	Α	
Pulsed Drain Current <sup>b</sup>	$I_{DM}$	±50			
Continuous Source Current (Diode Conduction) <sup>a</sup>		$I_S$	2.3	A	
D : a	T <sub>A</sub> =25°C	D	3.1	W	
Power Dissipation <sup>a</sup>	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	rD	2.2	<b>VV</b>	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to 150	°C	

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Maximum	Units		
M · I · · · a	t <= 10 sec	D	50	°C/W		
Maximum Junction-to-Ambient <sup>a</sup>	Steady State	$R_{ heta JA}$	92	°C/W		

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## Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

SPECIFICATIONS (T <sub>A</sub> = 25°C UNLESS OTHERWISE NOTED)							
Parameter Parameter	Symbol	Test Conditions	Limits			Unit	
Taranetei	Symbol	Test Conditions	Min	Typ	Max	CILL	
Static							
Cate-Threshold Voltage	VGS(th)	$V_{DS}=V_{GS}$ , $I_D=250$ uA	1			V	
Gate-Body Leakage	IGSS	$V_{DS} = 0 \text{ V}, V_{GS} = 20 \text{ V}$			±100	nA	
Zara Cata Valtaga Dmin Gurrant	Ipss	$V_{DS}=24 V$ , $V_{GS}=0 V$	1		1	T A	
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = 24 \text{ V}, V_{CS} = 0 \text{ V}, T_J = 55^{\circ}\text{C}$			25	uA	
On-State Drain Current <sup>A</sup>	I <sub>D(on)</sub>	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	20			Α	
- · · · · · · · · · · · · · · · · · · ·		$V_{GS} = 10 \text{ V}, I_D = 8.1 \text{ A}$			32		
Drain-Source On-Resistance <sup>A</sup>	fDS(on)	$V_{GS} = 4.5 \text{ V}, I_D = 6.9 \text{ A}$	44		mΩ		
Forward Tranconductance <sup>A</sup>	gs	$V_{DS} = 15 \text{ V}, I_D = 8.1 \text{ A}$		40		S	
Diode Forward Voltage	Vsd	$I_S = 2.3 A, V_{GS} = 0 V$		0.7		V	
Dynamic <sup>b</sup>	•				•	•	
Total Gate Charge	Qg	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V},$		12.5			
Gate-Source Charge	$Q_{gs}$	$I_{D} = 8.1 \mathrm{A}$		2.6		пC	
Gate-Drain Charge	Qgd	ID-8.1 A		4.6			
Switching	•				•		
Turn-On Delay Time	td(on)			20			
Rise Time	tr	$V_{DD}$ =25 V, $R_L$ =25 $\Omega$ , $I_D$ =1 A,		9		nS	
Turn-Off Delay Time	td(off)	VGEN = 10 V		70		113	
Fall-Time	tf			20			

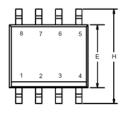
## Notes

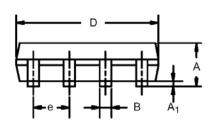
- a. Pulse test:  $PW \le 300us duty cycle \le 2\%$ .
- b. Guaranteed by design, not subject to production testing.

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## Package Information

SO-8: 8LEAD





	MILLIM	IETERS	INC	HES
Dim	Min	Max	Min	Max
Α	1.35	1.75	0.053	0.069
A <sub>1</sub>	0.10	0.20	0.004	0.008
В	0.35	0.51	0.014	0.020
С	0.19	0.25	0.0075	0.010
D	4.80	5.00	0.189	0.196
E	3.80	4.00	0.150	0.157
е	1.27	BSC	0.050	BSC
Н	5.80	6.20	0.228	0.244
h	0.25	0.50	0.010	0.020
L	0.50	0.93	0.020	0.037
q	0°	8°	0°	8°

